

**TLP624X, TLP624-2X, TLP624-4X
TLP624, TLP624-2, TLP624-4**



**LOW INPUT CURRENT
PHOTOTRANSISTOR
OPTICALLY COUPLED ISOLATORS**

APPROVALS

- UL recognised, File No. E91231

'X' SPECIFICATION APPROVALS

- VDE 0884 in 3 available lead form :-
 - STD
 - G form
 - SMD approved to CECC 00802

DESCRIPTION

The TLP624, TLP624-2, TLP624-4 series of optically coupled isolators consist of infrared light emitting diodes and NPN silicon photo transistors in space efficient dual in line plastic packages.

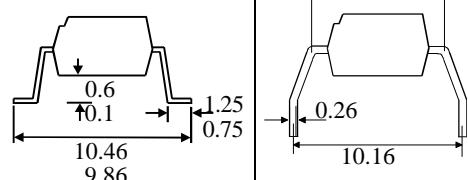
FEATURES

- Options :-
 - 10mm lead spread - add G after part no.
 - Surface mount - add SM after part no.
 - Tape&reel - add SMT&R after part no.
- High Current Transfer Ratio (50% min)
- High Isolation Voltage (5.3kV_{RMS}, 7.5kV_{PK})
- High BV_{CEO} (55Vmin)
- All electrical parameters 100% tested
- Low Input Current 0.5mA I_F

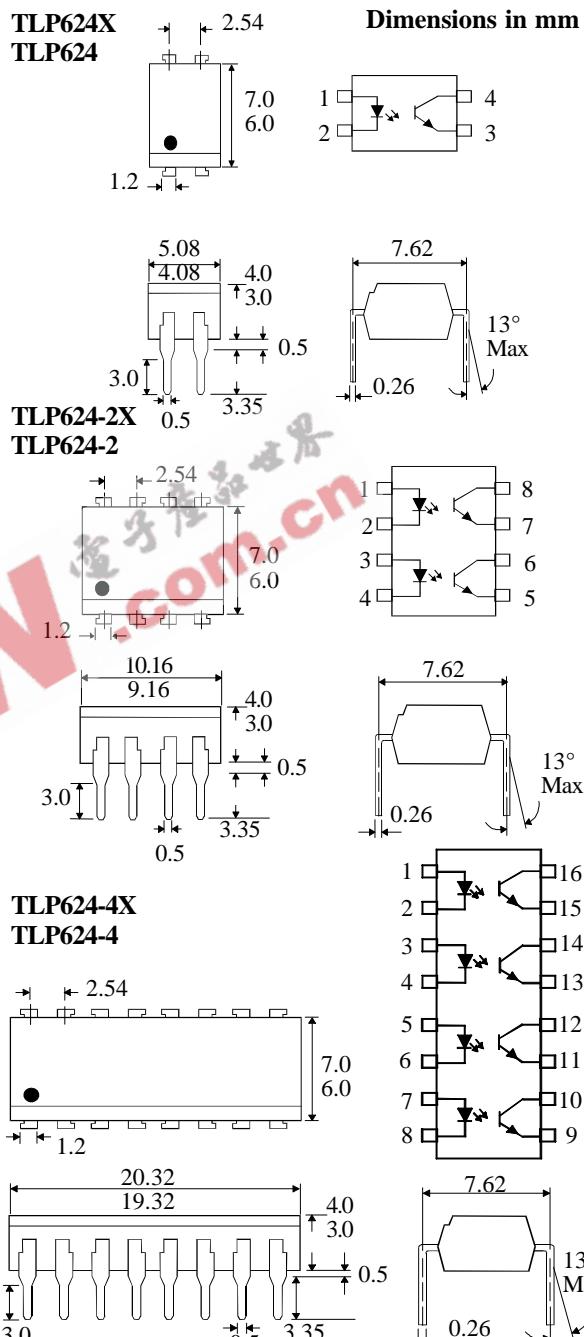
APPLICATIONS

- Computer terminals
- Industrial systems controllers
- Measuring instruments
- Signal transmission between systems of different potentials and impedances

**OPTION SM
SURFACE MOUNT**



OPTION G



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ABSOLUTE MAXIMUM RATINGS
(25°C unless otherwise specified)

Storage Temperature	-55°C to + 125°C
Operating Temperature	-55°C to + 100°C
Lead Soldering Temperature (1/16 inch (1.6mm) from case for 10 secs)	260°C

INPUT DIODE

Forward Current	50mA
Reverse Voltage	5V
Power Dissipation	70mW

OUTPUT TRANSISTOR

Collector-emitter Voltage BV _{CEO}	55V
Emitter-collector Voltage BV _{ECO}	6V
Power Dissipation	150mW

POWER DISSIPATION

Total Power Dissipation	200mW
(derate linearly 2.67mW/°C above 25°C)	

ELECTRICAL CHARACTERISTICS (T_A = 25°C Unless otherwise noted)

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage (V _F) Reverse Voltage (V _R) Reverse Current (I _R)	1.0 5	1.15	1.3 10	V V μA	I _F = 10mA I _R = 10μA V _R = 5V
Output	Collector-emitter Breakdown (BV _{CEO}) (Note 2) Emitter-collector Breakdown (BV _{ECO}) Collector-emitter Dark Current (I _{CEO})	55			V	I _C = 0.5mA
		6		100	V nA	I _E = 100μA V _{CE} = 24V
Coupled	Current Transfer Ratio (CTR) (Note 2) TLP624,TLP624-2,TLP624-4	100 50		1200	% %	1mA I _F , 0.5V V _{CE} 0.5mA I _F , 1.5V V _{CE}
	Collector-emitter Saturation Voltage V _{CE (SAT)}		0.2	0.4	V V	1mA I _F , 0.5mA I _C 1mA I _F , 1mA I _C
	Input to Output Isolation Voltage V _{ISO}	5300 7500			V _{RMS} V _{PK}	See note 1 See note 1
	Input-output Isolation Resistance R _{ISO}	5x10 ¹⁰			Ω	V _{IO} = 500V (note 1)
	Rise Time tr		8		μs	V _{CC} = 10V ,
	Fall Time tf		8		μs	I _C = 2mA, R _L = 100Ω
	Turn-on Time ton		10		μs	
	Turn-off Time toff		8		μs	

Note 1 Measured with input leads shorted together and output leads shorted together.

Note 2 Special Selections are available on request. Please consult the factory.

